

EMD6 / UMD6N / IMD6A

Transistors

General purpose (dual digital transistors)

EMD6 / UMD6N / IMD6A

●Features

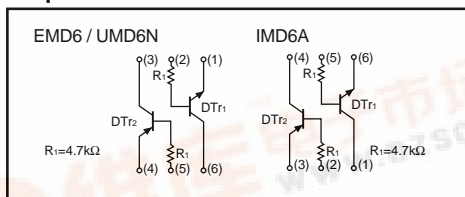
- 1) Both the DTA143T chip and DTC143T chip in an EMT or UMT or SMT package.
- 2) Mounting possible with EMT3 or UMT3 or SMT3 automatic mounting machines.
- 3) Transistor elements are independent, eliminating interference.
- 4) Mounting cost and area can be cut in half.

●Structure

A PNP and NPN digital transistor (each with a single built in resistor)

The following characteristics apply to both the DTr1 and DTr2, however, the “-” sign on DTr2 values for the PNP type have been omitted.

●Equivalent circuit

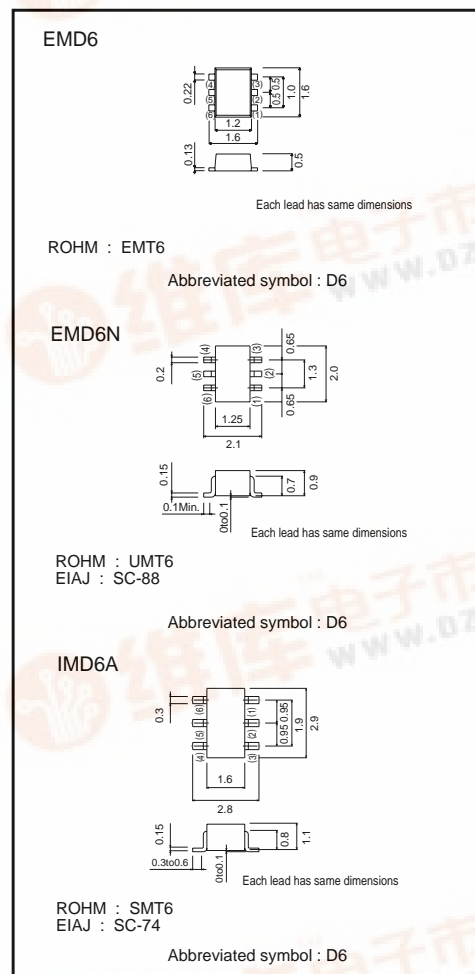


●Absolute maximum ratings (Ta = 25°C)

Parameter	Symbol	Limits	Unit
Collector-base voltage	V _{CB0}	50	V
Collector-emitter voltage	V _{CE0}	50	V
Emitter-base voltage	V _{EB0}	5	V
Collector current	I _c	100	mA
Collector power dissipation	EMD6, UMD6N	150 (TOTAL)	mW *1
	IMD6A	300 (TOTAL)	mW *2
Junction temperature	T _j	150	°C
Storage temperature	T _{stg}	-55~+150	°C

*1 120mW per element must not be exceeded.
*2 200mW per element must not be exceeded.

●External dimensions (Units : mm)



Transistors

●Electrical characteristics (Ta = 25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Collector-base breakdown voltage	BV _{CB0}	50	–	–	V	I _c =50μA
Collector-emitter breakdown voltage	BV _{CE0}	50	–	–	V	I _c =1mA
Emitter-base breakdown voltage	BV _{EB0}	5	–	–	V	I _E =50μA
Collector cutoff current	I _{CB0}	–	–	0.5	μA	V _{CB} =50V
Emitter cutoff current	I _{EB0}	–	–	0.5	μA	V _{EB} =4V
Collector-emitter saturation voltage	V _{CE(sat)}	–	–	0.3	V	I _c /I _B =5mA/0.25mA
DC current transfer ratio	h _{FE}	100	250	600	–	V _{CE} =5V, I _c =1mA
Transition frequency	f _T	–	250	–	MHz	V _{CE} =10mA, I _E =-5mA, f=100MHz *
Input resistance	R ₁	3.29	4.7	6.11	kΩ	–

* Transition frequency of the transistor

●Packaging specifications

Type	Package	Taping		
	Code	T2R	TR	T148
	Basic ordering unit (pieces)	8000	3000	3000
EMD6	○	—	—	—
UMD6N	—	○	—	—
IMD6A	—	—	—	○

●Electrical characteristic curves

DT_{r1} (NPN)

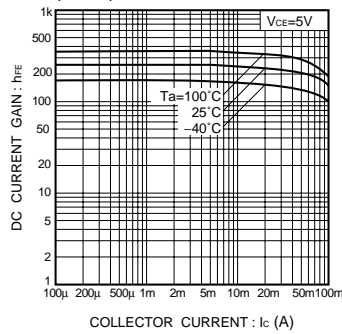


Fig.1 DC current gain vs. collector current

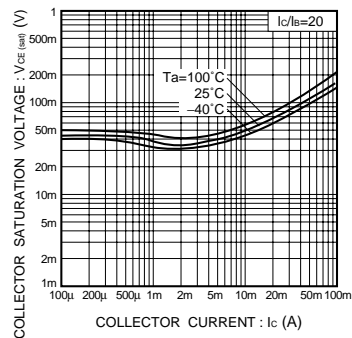


Fig.2 Collector-emitter saturation voltage vs. collector current

DT_{r2} (PNP)

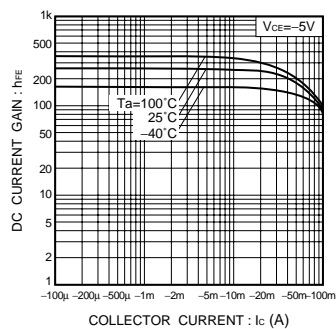


Fig.3 DC current gain vs. collector current

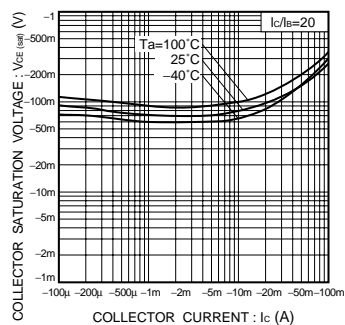


Fig.4 Collector-emitter saturation voltage vs. collector current